

### Vishay Semiconductors

# **Small Signal Fast Switching Diodes**



#### **FEATURES**

- Silicon epitaxial planar diode
- AEC-Q101 qualified
- Material categorization:
   For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

# Ph

RoHS

ROHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

· Extreme fast switches

#### **MECHANICAL DATA**

Case: DO-35

Weight: approx. 125 mg
Cathode band color: black
Packaging codes/options:

TR/10K per 13" reel (52 mm tape), 50K/box TAP/10K per ammopack (52 mm tape), 50K/box

PARTS TABLE						
PART	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS		
1N4154	1N4154TR or 1N4154TAP	1N4154	Single diode	Tape and reel/ammopack		

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage		V <sub>RRM</sub>	35	V		
Reverse voltage		V <sub>R</sub>	25	V		
Peak forward surge current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	2	Α		
Repetitive peak forward current		I <sub>FRM</sub>	500	mA		
Forward continuous current		I <sub>F</sub>	300	mA		
Average forward current	V <sub>R</sub> = 0	I <sub>F(AV)</sub>	150	mA		
Dower dissination	I = 4 mm, T <sub>L</sub> = 45 °C	P <sub>tot</sub>	440	mW		
Power dissipation	I = 4 mm, T <sub>L</sub> ≤ 25 °C	P <sub>tot</sub>	500	mW		

THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to ambient air	I = 4 mm, T <sub>L</sub> = constant	R <sub>thJA</sub>	350	K/W		
Junction temperature		Tj	175	°C		
Storage temperature range		T <sub>stg</sub>	- 65 to + 175	°C		



#### www.vishay.com

## Vishay Semiconductors

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 30 mA	V <sub>F</sub>		0.88	1	V
Reverse current	V <sub>R</sub> = 25 V	I <sub>R</sub>		9	100	nA
neverse current	V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			100	μA
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V <sub>(BR)</sub>	35			V
Diode capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $V_{HF} = 50 \text{ mV}$	C <sub>D</sub>			4	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}$	+			4	ns
neverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $i_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t <sub>rr</sub>			2	

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

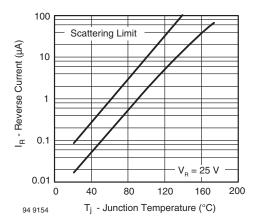


Fig. 1 - Reverse Current vs. Junction Temperature

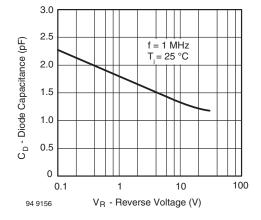


Fig. 3 - Diode Capacitance vs. Reverse Voltage

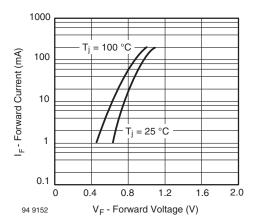
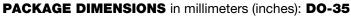
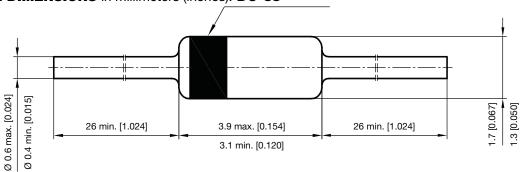


Fig. 2 - Forward Current vs. Forward Voltage

# Vishay Semiconductors





Rev. 6 - Date: 19. December 2011 Document no.: SB-V-3906.04-031(4)

94 9366



### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 13-Jun-16 1 Document Number: 91000

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

<u>1N4154TR</u> <u>1N4154TAP</u>